

Template synthesis of defect-rich MoS₂-based assemblies as electrocatalytic platforms for hydrogen evolution reaction

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Defect-rich MoS₂ nanostructures were synthesized in solution by a microwave-assisted process, employing either a sacrificial soft template (CaCO₃) or a non-sacrificial hard template (graphene oxide) and the electrocatalytic performance towards the hydrogen evolution reaction was found to be superior for the latter.

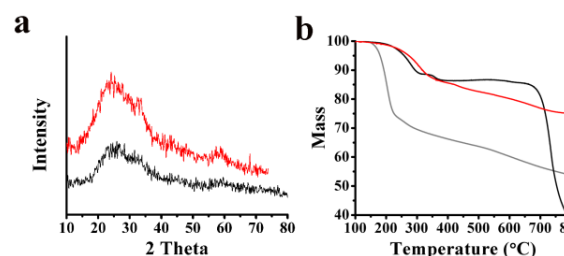
Transition metal dichalcogenides (TMDs) possess a stacked arrangement, in which atomic metal sheets are sandwiched by chalcogen ones, forming a 2D layered framework. When the multiple weak van der Waals interactions keeping together those layers are overcome, chemical exfoliation from the bulk occurs yielding few-layered TMDs. In fact, depending on the agents employed for the exfoliation process, diverse polytypes of TMDs are obtained, possessing metallic or semiconducting properties.¹⁻⁴ Considering merits attributed to electrocatalytic properties and stability, TMDs recently received high interest for the hydrogen evolution reaction (HER).⁵⁻¹⁶ This is mainly due to specific characteristics of TMDs, the high electrical conductivity along the TMD layer and the tunable electronic properties.¹⁷ Furthermore, the HER activity for TMDs stems from defect sites, mainly located in the periphery, contrasting the catalytically inert basal planes.¹⁸ Interestingly, the population of defect sites may be adjusted by the adopted synthetic bottom-up approach of TMDs and/or the presence of an additional component, playing the role of electrocatalyst substrate. The introduction of defects at MoS₂ enhances electrocatalytic activity by cracking the crystal and consequently increasing the accessible internal surface area.^{19, 20} Therefore, in order to enhance the electrocatalytic properties of TMDs, it is important to develop novel TMD-based nanostructures with higher number of exposed catalytic sites.²¹

Of all the general protocols for preparing TMD-based nanostructures with a structural motif bearing an increased density of active sites, the most popular ones concern low temperature and short-time processes, in solvothermal reduction reactions of a precursor salt. Specifically, microwave-assisted reduction of ammonium tetrathiomolybdate (ATTM) in DMF yielded MoS₂-based nanostructures with variable stacking order at 190-260 °C.^{8, 22} In parallel, the promotion of heterogeneous nucleation/growth of MoS₂ in liquid phase occurs in the presence of a hard template, such as oxidized carbon nanotubes²³ or graphene oxide sheets.^{22, 24, 25} However, it is not known and surely deserves investigation the utilization of sacrificial templates en route the preparation of MoS₂-based nanostructures, under microwave conditions. In addition, although the structural and electrocatalytic properties of the aforementioned MoS₂-based hybrids with graphitic components were adequately addressed, a detailed study on the effect of

component composition to the HER electrocatalytic activity has yet to be performed and assessed.

Considering the aforementioned points, the aim of the current work was the template synthesis of defect-rich MoS₂ nanosheets, with high specific surface area and subsequently their evaluation as HER electrocatalysts. Specifically, to realize this aim, we report the microwave-assisted bottom-up synthesis of MoS₂ in the presence of CaCO₃ as template, which can be selectively removed by acidic treatment. In parallel, the preparation of MoS₂-based nanostructures by employing graphene oxide (GO) as hard template was accomplished. The effect of the starting composition of the agents utilized, on the morphology and electrocatalytic activity of the MoS₂-based materials, was screened by examining different mass ratios between the inorganic precursor ATTM (employed in different concentrations 1-10 mg/mL) and the template (for details see ESI).

The synthetic protocol for preparing defect-rich MoS₂ was based on the microwave-assisted reduction of ATTM in



solvothermal conditions at 230 °C. The wetting medium, DMF, played the role of reducing agent as its absence did not allow the formation of MoS₂. The sacrificial template CaCO₃, which was added in relative excess (two- to four-fold compared to ATTM), allowing the growth of MoS₂ within the confined space between CaCO₃ crystallites, was removed by acidic treatment to obtain MoS₂ nanostructures with variable morphology. Conversely, when using GO as “hard” template, MoS₂/reduced graphene oxide (rGO) nanostructures were obtained, due to thermal deoxygenation of the graphitic lattice.²⁶ Different ATTM_x/GO_y amounts and mass ratios were treated under microwave irradiation, where x and y denote the corresponding mass of each component employed. Six different materials **1-6** were synthesized, by reacting ATTM₂₀/GO₁₂, ATTM₁₀/GO₆, ATTM₅/GO₃, ATTM₅/GO₆, ATTM₂₅/GO₆, and ATTM₅₀/GO₆, respectively (see ESI for details).

X-ray diffraction from MoS₂-based nanostructures (**Fig. 1a**), gave a clear picture about the amorphous character of the stacked nanosheets. This is in full agreement with a recent work,⁸ which demonstrated that MoS₂ crystallinity was enhanced at even higher temperatures than those currently employed. In addition, no

stacking order was observed for rGO. Notably, the UV-Vis electronic absorption spectra of MoS₂/rGO hybrids lack the characteristic excitonic bands attributed to the semiconducting polytype. Instead, a broad absorption band in the visible region occupies the spectra (Fig. S1), showcasing the metallic character of MoS₂ in all 1-6 hybrids.

The thermal stability of MoS₂ derived by the sacrificial template approach (sa-MoS₂), was examined by thermogravimetric analysis (TGA) under N₂. In Fig. S2, TGA profiles of the different sa-MoS₂ synthesized are presented and compared. It was observed that three sa-MoS₂ samples, prepared by the same starting concentration of ATTm with the one employed for untemplated MoS₂, were found to decompose appreciably up to 800 °C, with a total mass loss in the range 22-29 %. In sharp contrast, untemplated MoS₂ showed a corresponding mass loss of about 60% (Fig. 1b). Such thermal profiles implied the existence of defect sites at the MoS₂ lattice, since parent bulk MoS₂ powder shows enhanced thermal stability.²⁷ Furthermore, the thermal stability of MoS₂/rGO hybrids 1-6 as obtained by the “hard template” approach, was assessed by TGA. In Fig. 1b, the TGA profiles of reference samples, MoS₂ synthesized in the absence of a template under microwave conditions and neat GO powder, as well as MoS₂/rGO 1 are presented and compared. The TGA graphs for materials 2-6 are shown at ESI (Fig. S3). For GO, a 30% mass loss was observed at 150-350 °C, where the majority of the oxygen-related functionalities are thermally detached by the graphitic surface.²⁸ Further mass loss was mainly attributed to potential thermal decomposition of defected carbon network. As expected, MoS₂/rGO hybrids exhibited lower mass loss percentages, when compared to the reference sample of GO, due to the absence of oxygen-containing labile groups. Assuming that at 200-800 °C the vast majority of the observed mass loss in the hybrids is attributed to the defected MoS₂-based nanostructures, a rough calculation of MoS₂ wt% content can be done for each hybrid. For example, 1 was found to contain about 40 wt% MoS₂. On the contrary, material 5 seems to contain almost double amount, approximately 75 wt%, of the inorganic component.

To confirm the deoxygenation of graphitic lattice leading to reduction of graphene oxide to rGO, we performed vibrational spectroscopy measurements. In the IR spectrum of GO, typical bands corresponding to various stretching modes of C-O (at 1036 and 1220 cm⁻¹), C=C (at 1627 cm⁻¹) and C=O bonding (at 1715 cm⁻¹) were evident (ESI, Fig. S4). After the microwave-assisted process, it was clear that in material 1 the bands corresponding to the carbon-oxygen bonding were disappeared, implying an efficient deoxygenation of the graphitic surface. The efficient reduction of the GO template during the microwave-assisted growth of MoS₂ nanostructures was further supported by Raman spectroscopy.

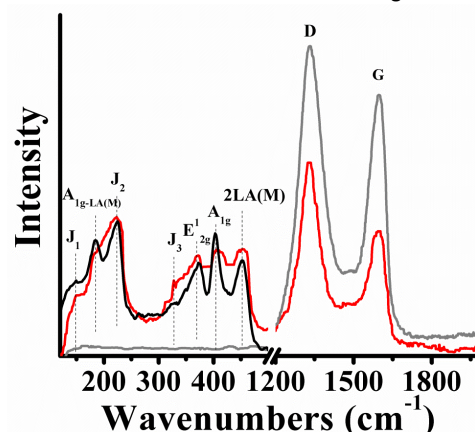
Fig. 1 (a) X-ray diffraction profiles for MoS₂/rGO material 1 (red) and MoS₂ obtained by the sacrificial template approach (sa-MoS₂, black). (b) TGA graphs for MoS₂/rGO material 1 (red), untemplated MoS₂ (black) and GO (grey), obtained under N₂ flow.

Raman spectra (λ_{exc} 633 nm) of sa-MoS₂ revealed characteristic modes of MoS₂-based nanostructures (Fig. S5), regardless of the starting composition of the components. In more detail, bands of MoS₂ at 373, 404 and 452 cm⁻¹ were recorded, corresponding to in-

plane E_{2g}¹, out-of-plane A_{1g} and 2LA(M) mode, respectively. The latter one was associated with disorder and defects. In addition, bands of MoS₂ at lower frequencies assigned to the A_{1g}(M)-LA(M) mode at 184 cm⁻¹ and J₁, J₂ and J₃ modes at 150, 224 and 325 cm⁻¹, respectively, were identified. Notably, the J₁-J₃ phonon modes unveil the metallic polytype 1T-MoS₂,²⁹ which was also manifested by UV-Vis electronic absorption spectroscopy – *vide supra*. Concerning MoS₂/rGO, Raman spectra revealed characteristic modes due to both components, regardless of the ratio employed between the inorganic precursor ATTm and GO for the preparation of the hybrid. Specifically, in the Raman spectrum of 1 (Fig. 2), the aforementioned characteristic bands owed to MoS₂ were observed. Similar vibrational modes were also observed for untemplated MoS₂. Furthermore, focusing in the frequency range of C-C vibrations, the characteristic D and G bands of rGO were present at 1329 and 1598 cm⁻¹, respectively. The intensity ratio of those two bands, I_{D/G}, was found to be 1.6, enhanced by 25 % as compared to the one registered for intact GO (i.e. 1.28). The latter was expected, since microwave irradiation employed for the preparation of the hybrid material resulted to simultaneous removal of the oxygen-related species on GO, with subsequent establishment of small conductive graphene islands.³⁰ The Raman spectra of the different MoS₂/rGO hybrid materials 2-6 presented similar features with those of 1 (Fig. S6).

Fig. 2 Raman spectra (633 nm) for MoS₂/rGO hybrid material 1 (red), untemplated MoS₂ (black) and GO (grey).

The morphology of the MoS₂/rGO nanostructures was assessed by electron microscopy imaging. Specifically, Fig. 3a shows a typical SEM image of material 1. From the extensive imaging performed, it was clear that the majority of nanostructures were entangled graphene sheets with a minor content of inorganic component –



see an isolated island of a MoS₂-based assembly in Fig. 3a. The stacking motif of MoS₂ sheets supported onto graphitic lattice was assessed by TEM imaging. Curled assemblies of intertwined inorganic flakes were observed for material 1 (Fig. 3b), which is a strong indication for the presence of defect-rich MoS₂ component. Similar assemblies were observed for 5 (Fig. 3c). Conversely, when the sacrificial template CaCO₃ was employed in the microwave-assisted reduction of ATTm salt to MoS₂, the latter was isolated after extensively washing the adduct with acidic water. The morphology of the resulting nanostructures sa-MoS₂ is presented in

Fig. 3d. The majority of the objects identified were small-sized aggregated nanoparticles. The small size may be explained considering that MoS₂ growth occurs in a somewhat confined environment, in the vicinity of excess CaCO₃ crystallites within the liquid medium. Beyond the those small-sized nanostructures for sa-MoS₂, one-dimensional nanorods were also observed (**Fig. 3e, f**). The length of these morphologies ranged to be 200 nm - 10 μm, while their diameter was approximately 20-100 nm. Additional TEM images of such sa-MoS₂ rod-like nanostructures are illustrated at the ESI (Fig. S7).

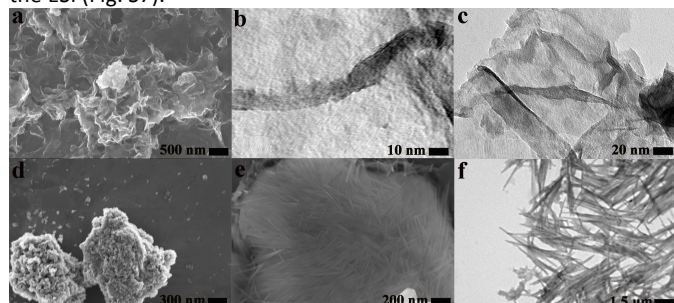
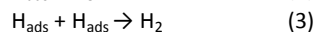
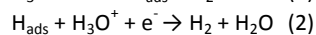
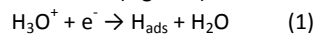


Fig. 3 (a) SEM image of MoS₂/rGO **1**. (b, c) TEM images of **1** and **5**, respectively. (d, e) SEM images of sa-MoS₂ showing small-sized aggregated nanoparticles, and nanorod morphology, respectively. (f) TEM image of sa-MoS₂ with nanorod morphology.

The electrocatalytic activity towards HER for all hybrid materials was investigated by linear sweep voltammetry (LSV). The assays were performed with a rotating-disc working glassy carbon electrode in a standard three-electrode glass cell at a scan rate of 5 mV/sec in N₂ saturated 0.5 M H₂SO₄. **Fig. 4a** and Fig. S8a illustrate polarization curves for the different MoS₂/rGO hybrids, in comparison with those of untemplated MoS₂, sa-MoS₂, GO and commercial Pt (20% on carbon). Apparently, the electrocatalytic activity of MoS₂/rGO hybrids **1-6** was significantly increased compared to that of untemplated MoS₂, sa-MoS₂ and GO, as evidenced by the increase of the cathodic current at a given potential. Markedly, the highest onset overpotential among the different MoS₂/rGO hybrids was registered for **1** at -0.09 V vs RHE (**Fig. 4b**), shifted by 300 mV to more positive potentials as compared to that of untemplated MoS₂, appearing at -0.390 V vs RHE and Pt exhibiting the highest HER catalytic performance at 0.026 V overpotential. **Fig. 4b** and Fig. S8b summarize the onset overpotentials for all tested materials, showcasing the beneficial role of rGO for enhancing the electrocatalytic activity of MoS₂ towards HER under optimized conditions. Noting that the amount of cathodic current density is proportional to the amount of hydrogen evolved and since HER electrocatalysts are commonly compared against overpotential at a cathodic current density of 10 mA/cm², **Fig. 4c** and Fig. S8c collectively illustrate a graph of those parameters for all materials. Again, **1** exhibited among all tested hybrids the best electrocatalytic activity at 0.154 V, by showing a more positive potential by 476 mV as compared to that of untemplated MoS₂ at the cathodic current density of 10 mA/cm². Overall, the enhanced electrocatalytic activity for MoS₂ hybridized with rGO is attributed to a combination of factors, namely the metallic nature of MoS₂ and intimate contact with rGO, the absence of any organic species and/or surfactants, and the enhanced number of exposed edge sites in MoS₂.

In order to decode the HER mechanism and determine the rate limiting step, the Tafel slope for all tested materials was extracted from the LSV polarization curves and presented in **Fig. 4d** and Fig. S8d. Briefly, all MoS₂/rGO hybrids exhibited smaller Tafel slope as compared to that owed to untemplated MoS₂ and sa-MoS₂, indicating that for the generation of an equivalent current only a lower overpotential is required. Hence, the electrocatalytic activity of MoS₂/rGO was enhanced in comparison to untemplated MoS₂ and sa-MoS₂, which can be rationalized by considering good electrical contact between the two species within the MoS₂/rGO hybrid. Generally, three possible reaction steps are considered for the HER in acidic media.³¹ First, the adsorption of a proton onto the electrode surface via a reduction process (Volmer adsorption equation 1) takes place. Next, bonding of the adsorbed hydrogen with a proton and electron transfer from the electrode surface (Heyrovsky desorption equation 2), or recombination of two hydrogen atoms adsorbed on the electrode surface (Tafel desorption equation 3), occurs. Based on the tabulated Tafel slope values given in **Fig. 4e**, the electrochemical desorption of adsorbed hydrogen atoms from the modified electrode surface governs the rate limiting step for MoS₂/rGO hybrid material **1**. On the contrary, the Tafel slope for untemplated MoS₂ and sa-MoS₂, is higher, attributing the rate-limiting step to the adsorption of hydrogen onto the electrode surface. Similar is the situation for MoS₂/rGO materials **2-6** (Fig. S8e).



In order to shed light on the enhanced electrocatalytic activity of the MoS₂/rGO hybrid materials, the electrochemically active surface area (ECSA) was calculated (see ESI for details) by performing cyclic voltammetry in a non-Faradaic region at different scan rates (Fig. S9). Apparently, the ECSA values of MoS₂/rGO were significantly higher than that of untemplated MoS₂ and sa-MoS₂ (ESI, Table S1). In line with the rest electrochemical results, **1** exhibits the higher ECSA value – note that hybrids with higher ECSA values indicate more effective accessibility of the active sites, similarly with recent reports.³² Lastly, durability studies were performed to evaluate their long-term stability. To assess this, continuous cyclic voltammograms were implemented (Fig. S10), where negligible loss of the cathodic current was observed for all tested materials. The various HER parameters before and after 1000 cycles are summarized in Table S1.

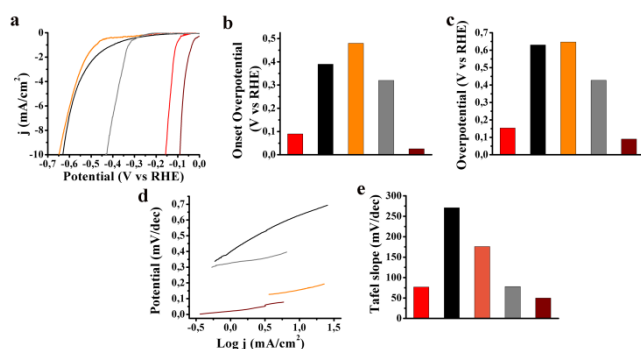


Fig. 4 (a) LSV for HER polarization curves. (b, c) Graphs for onset overpotential, and overpotential registered at -10 mA/cm² current

density, respectively. (**d, e**) Tafel slopes, and tabulated values. Color code: MoS₂/rGO material **1** (red), untemplated MoS₂ (black), sa-MoS₂ (orange), GO (grey), and Pt/C (wine).

In summary, the microwave-assisted synthesis of defect-rich MoS₂ nanostructures by adopting a sacrificial template approach based on CaCO₃ and a hard template one based on GO was studied. The starting composition of precursor components was varied in a wide range of mass ratios. Among the tested nanostructures as HER electrocatalysts, the optimized MoS₂/rGO material **1** showed improved electrocatalytic performance, requiring an overpotential of 154 mV at a current density of 10 mA/cm² and showing a Tafel slope of 77 mV/dec. The enhanced electrocatalytic functioning of MoS₂/rGO was ascribed to the (a) metallic nature of MoS₂ and intimate contact with rGO, (b) the absence of any organic species and/or surfactants, and (c) the enhanced number of exposed edge sites in MoS₂. The higher ECSA value for **1** points out the large functioning surface area of the catalytic active sites and the excellent hydrogen production ability that leads to superior catalytic performance. Furthermore, examination of the Tafel slopes, manifested the adsorption of hydrogen as the rate-limiting step for hydrogen generation.

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Conflicts of interest

There are no conflicts to declare.

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